NSN 5961-01-371-8899

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-371-8899 **Inclosure Material:** Glass **Overall Length:** 0.310 inches **Terminal Length:** 1.300 inches **Overall Diameter:** Between 0.155 inches and 0.215 inches **Mounting Method:** Terminal Features Provided: Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 2000.0 working peak reverse voltage and 3.5 forward voltage, peak **Current Rating Per Characteristic:** 2.00 amperes forward current, average absolute and 100.00 amperes forward current, average preset and 15.00 amperes forward current, average blank **Capacitance Rating In Picofarads:** 250.0 **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Special Features:** Ultra fast recovery **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No